

DATA SHEET

BYC10B-600

Rectifier diode

ultrafast, low switching loss

Product specification

August 2018



WeEn

WeEn Semiconductors

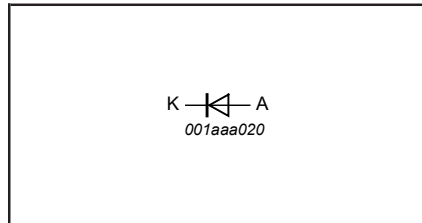
Rectifier diode ultrafast, low switching loss

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FEATURES

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

SYMBOL



QUICK REFERENCE DATA

$V_R = 600\text{ V}$
$V_F \leq 1.8\text{ V}$
$I_{F(AV)} = 10\text{ A}$
$t_{rr} = 19\text{ ns (typ)}$

APPLICATIONS

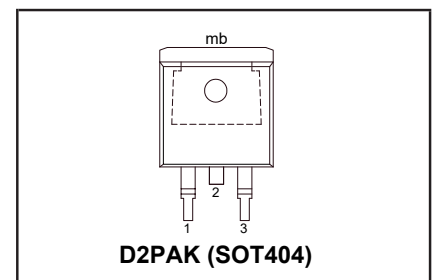
- Active power factor correction
- Half-bridge lighting ballasts
- Half-bridge/ full-bridge switched mode power supplies.

The BYC10B-600 is supplied in the SOT404 surface mounting package.

PINNING

PIN	DESCRIPTION
1	no connection
2	cathode ¹
3	anode
tab	cathode

SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	Peak repetitive reverse voltage		-	600	V
V_{RWM}	Crest working reverse voltage		-	600	V
V_R	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current	$T_{mb} \leq 114\text{ °C}$ $\delta = 0.5$; with reappplied $V_{RRM(max)}$;	-	10	A
I_{FRM}	Repetitive peak forward current	$T_{mb} \leq 78\text{ °C}$ $\delta = 0.5$; with reappplied $V_{RRM(max)}$;	-	20	A
I_{FSM}	Non-repetitive peak forward current.	$T_{mb} \leq 78\text{ °C}$ $t = 10\text{ ms}$ $t = 8.3\text{ ms}$ sinusoidal; $T_j = 150\text{ °C}$ prior to surge with reappplied $V_{RWM(max)}$	-	65 71	A A
T_{stg}	Storage temperature		-40	150	°C
T_j	Operating junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base		-	-	2	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

¹ it is not possible to make connection to pin 2 of the SOT404 package

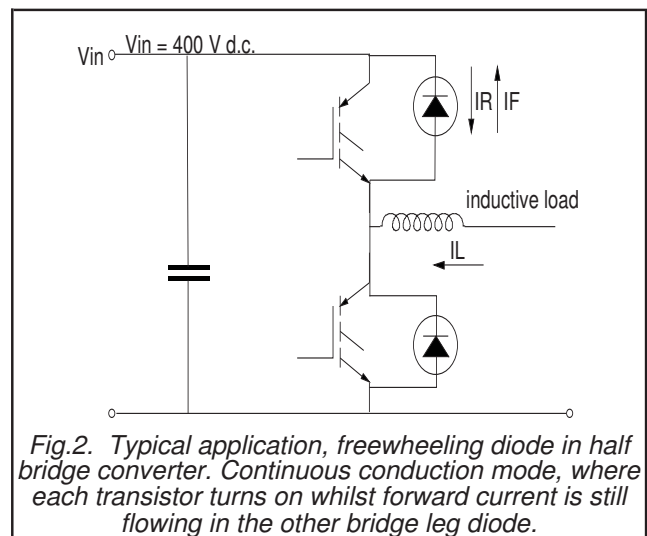
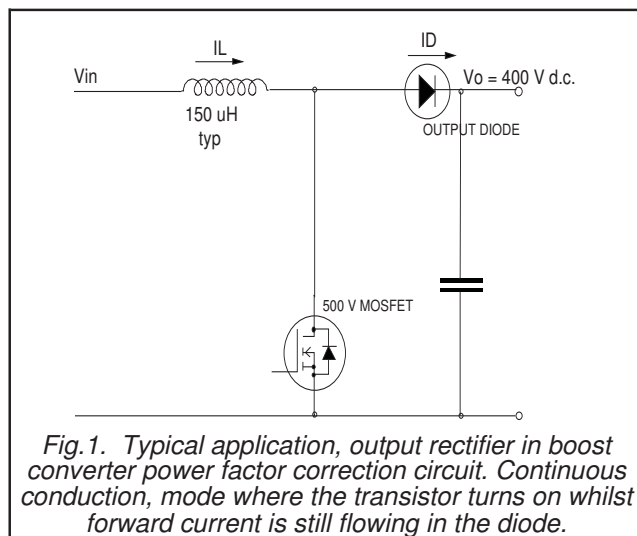
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ELECTRICAL CHARACTERISTICS

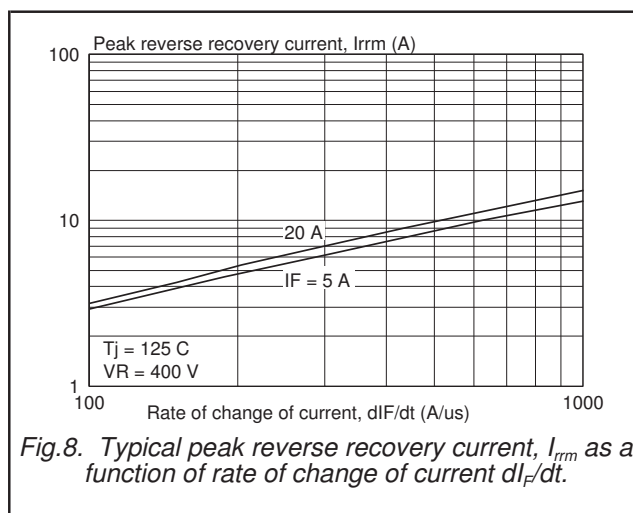
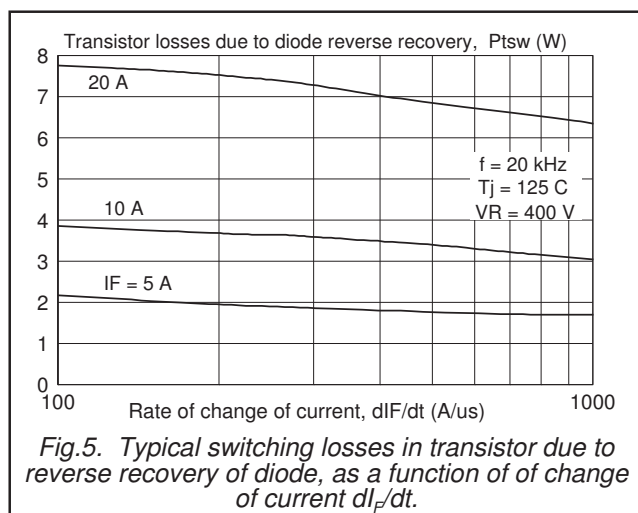
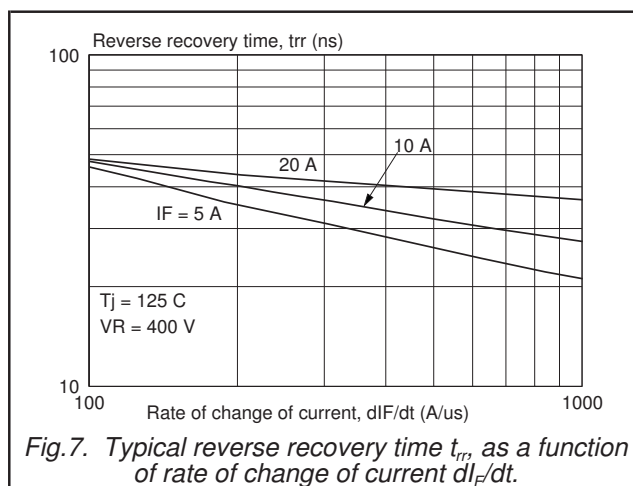
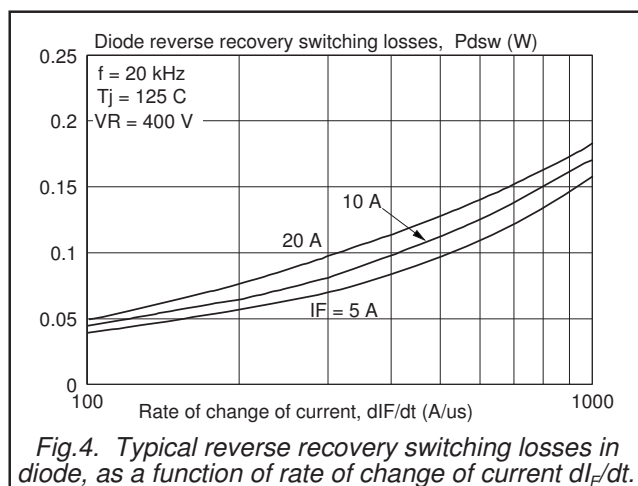
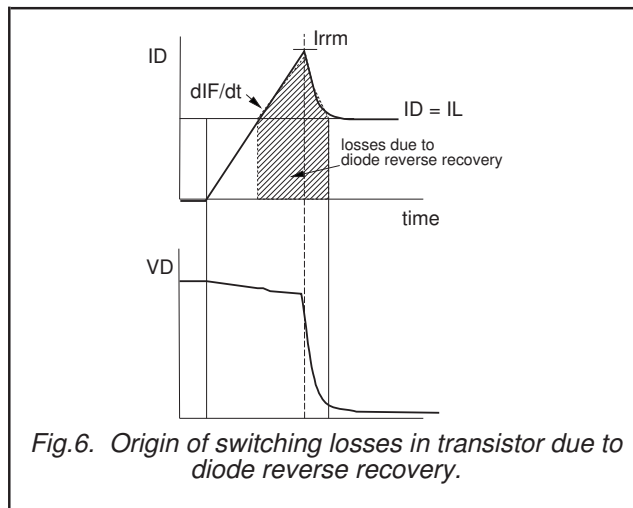
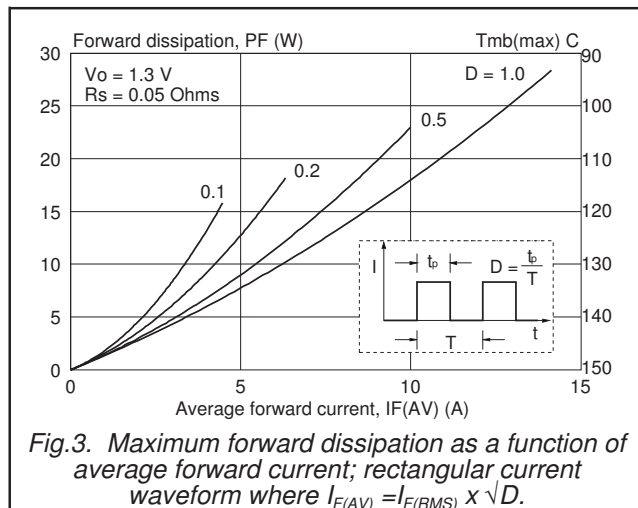
 $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 10\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$	-	1.4	1.8	V
		$I_F = 20\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$	-	1.7	2.3	V
I_R	Reverse current	$I_F = 10\text{ A};$ $V_R = 600\text{ V}$	-	2.0	2.9	V
		$V_R = 500\text{ V}; T_j = 100\text{ }^{\circ}\text{C}$	-	9	200	μA
			-	1.1	3.0	mA
t_{rr}	Reverse recovery time	$I_F = 1\text{ A}; V_R = 30\text{ V}; dI_F/dt = 50\text{ A}/\mu\text{s}$	-	35	55	ns
t_{rr}	Reverse recovery time	$I_F = 10\text{ A}; V_R = 400\text{ V};$ $dI_F/dt = 500\text{ A}/\mu\text{s}$	-	19	-	ns
t_{rr}	Reverse recovery time	$I_F = 10\text{ A}; V_R = 400\text{ V};$ $dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 100\text{ }^{\circ}\text{C}$	-	32	40	ns
I_{rrm}	Peak reverse recovery current	$I_F = 10\text{ A}; V_R = 400\text{ V};$ $dI_F/dt = 100\text{ A}/\mu\text{s}; T_j = 125\text{ }^{\circ}\text{C}$	-	3	7.5	A
I_{rrm}	Peak reverse recovery current	$I_F = 10\text{ A}; V_R = 400\text{ V};$ $dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 125\text{ }^{\circ}\text{C}$	-	9.5	12	A
V_{fr}	Forward recovery voltage	$I_F = 10\text{ A}; dI_F/dt = 100\text{ A}/\mu\text{s}$	-	8	11	V



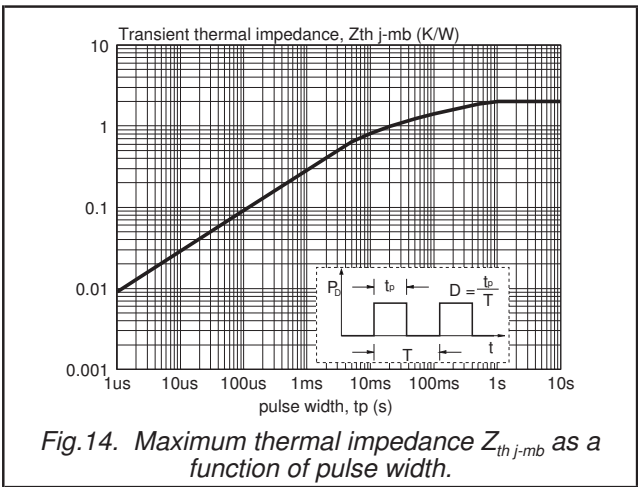
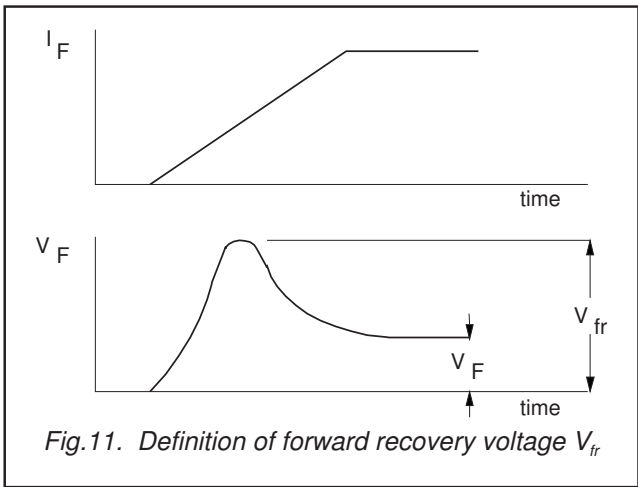
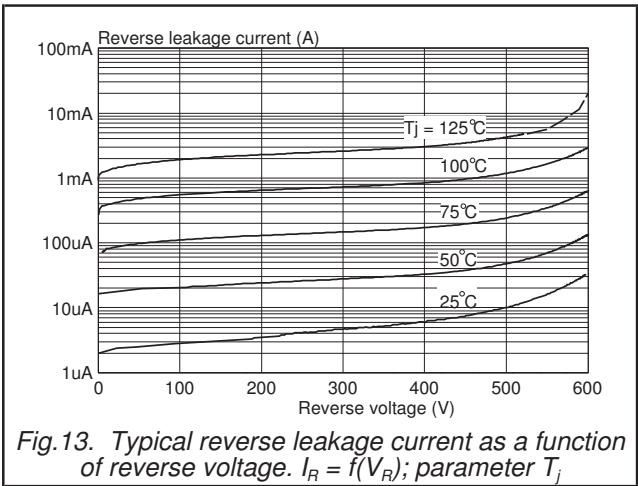
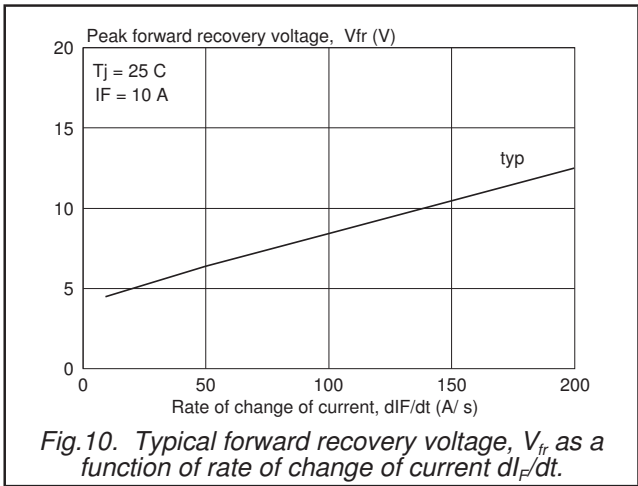
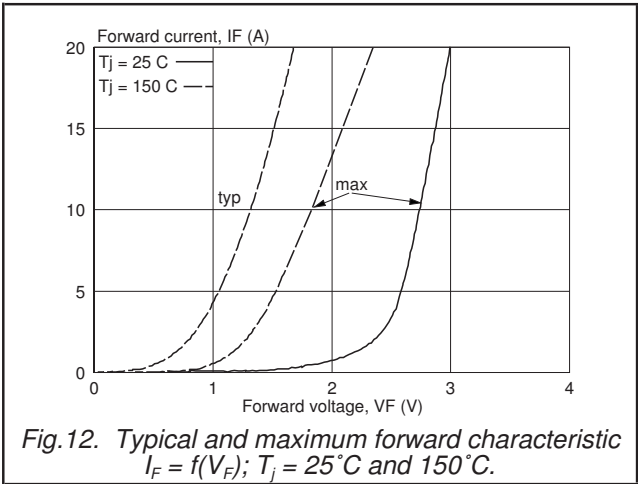
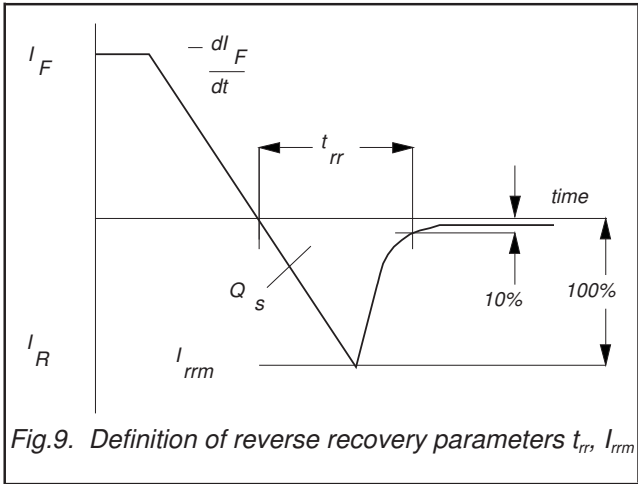
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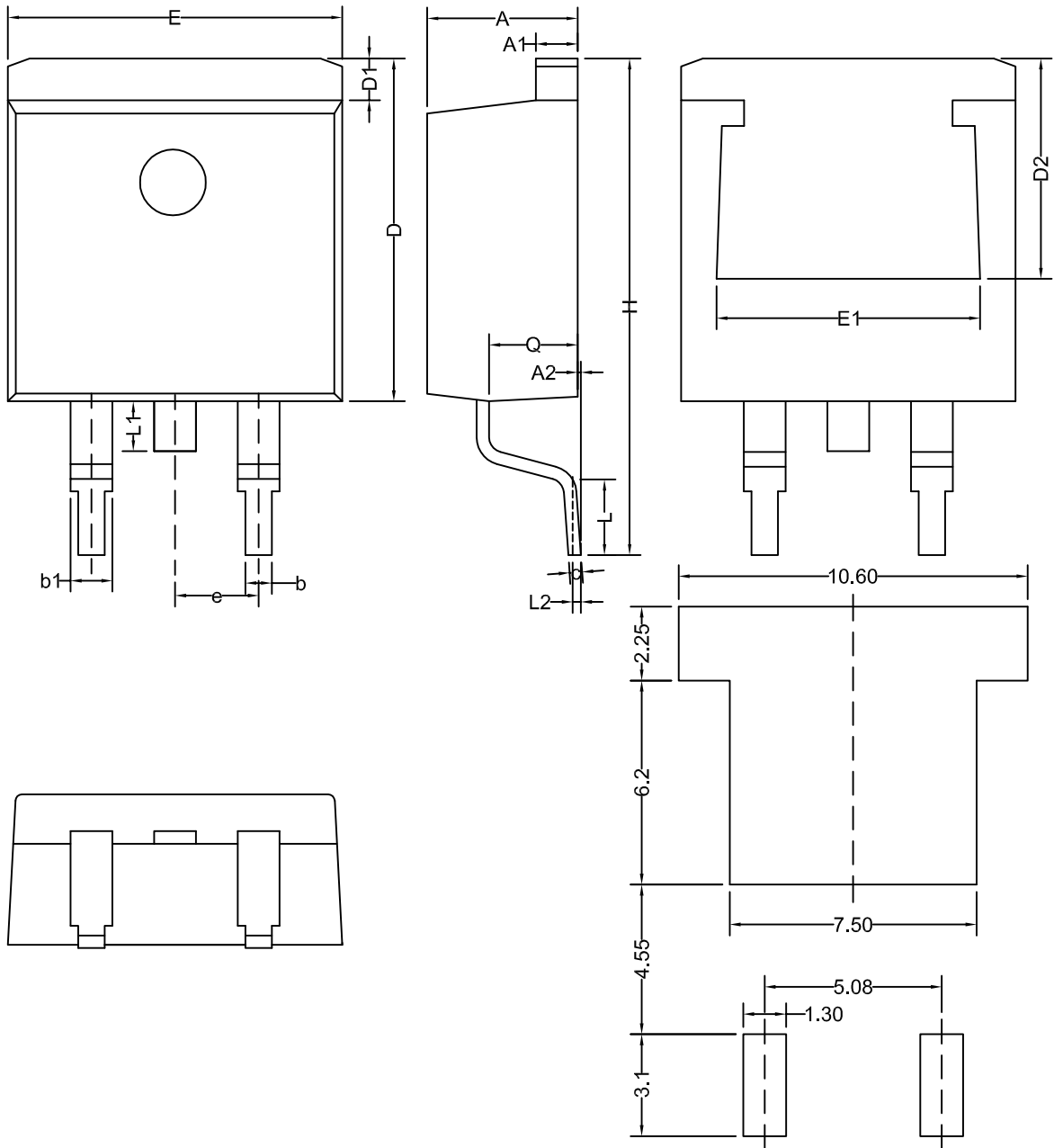
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MECHANICAL DATA

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

TO263



Recommended Footprint

	A	A1	A2	b	b1	c	D	D1	D2	e	E	E1	H	L	L1	L2	Q
min	4.10	1.22	0.00	0.60	1.05	0.34	---	1.20	6.60	2.54 (BSC)	9.70	7.80	14.80	2.10	---	0.25 (BSC)	2.20
max	4.70	1.40	0.25	0.90	1.45	0.64	11.00	1.60	---	---	10.30	---	15.80	2.90	1.75	---	2.79

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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